# NSN 5961-01-332-8080

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## **Overall Length:**

Between 0.072 inches and 0.078 inches

## **Overall Height:**

Between 0.030 inches and 0.040 inches

## **Overall Width:**

Between 0.037 inches and 0.043 inches

## Internal Configuration:

Junction contact

#### **Mounting Method:**

Terminal

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

60.0 collector to base voltage/static/emitter open and 60.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage,

#### static, collector open

## **Current Rating Per Characteristic:**

200.00 milliamperes source cutoff current

## **Power Rating Per Characteristic:**

0.28 watts small-signal input power, common-collector

#### **Transfer Ratio:**

50.0 static forward current transfer ratio, common-emitter

## Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: pnp

## **Precious Material And Location:**

Eutectie die bonds surfaces terminals and land areas surfaces gold

#### **Precious Material:**

Gold

**Terminal Type And Quantity:** 

4 bonding pad

Shelf Life:

N/a

#### Unit Of Measure:

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Demilitarization:

No

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